

250MHZ CMOS Rail-to-Rail Output Opamps

Features

• Single-Supply Operation from +2.5V ~ +5.5V

• Rail-to-Rail Output

• -3dB Bandwidth(G=+1): 250MHz (Typ)

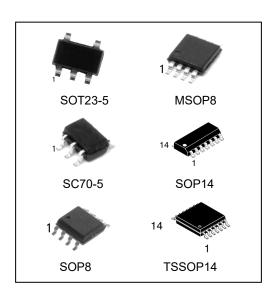
• Low Input Bias Current: 1pA (Typ)

• Quiescent Current: 2.8mA/Amplifier (Typ)

Operating Temperature: -40°C ~ +125°C

Small Package:

HGV8051 Available in SOT23-5 and SC70-5 Packages HGV8052 Available in SOP-8,MSOP-8 and DFN-8 Packages HGV8054 Available in SOP-14 and TSSOP-14 Packages



Ordering Information

DEVICE	Package Type	MARKING	Packing	Packing Qty
HGV8051M5/TR	SOT23-5	8051	REEL	3000pcs/reel
HGV8051M7/TR	SC70-5	8051	REEL	3000pcs/reel
HGV8052M/TR	SOP8	V8052	REEL	2500pcs/reel
HGV8052MM/TR	MSOP8	8052	REEL	3000pcs/reel
HGV8052DQ/TR	DFN8	8052	REEL	3000pcs/reel
HGV8054M/TR	SOP14	HGV8054	REEL	2500pcs/reel
HGV8054MT/TR	TSSOP14	V8054	REEL	2500pcs/reel



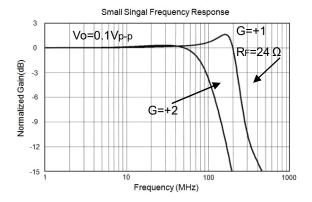
General Description

The HGV8051(single), HGV8052(dual), HGV8054(quad) are rail-to-rail output voltage feedback amplifiers offering ease of use and low cost. They have bandwidth and slew rate typically found in current feedback amplifiers. All have a wide input common-mode voltage range and output voltage swing, making them easy to use on single supplies as low as 2.5V. Despite being low cost, the HGV805X series provide excellent overall performance. They offer wide bandwidth to 250 MHz (G = +1) along with 0.1dB flatness out to 52 MHz (G = +2) and offer a typical low power of 2.8 mA/amplifier.

The HGV805X series is low distortion and fast settling make it ideal for buffering high speed A/D or D/A converters. The HGV8051 has a power-down disable feature that reduces the supply current to 50μ A. These features make the HGV8051/2 ideal for portable and battery-powered applications where size and power are critical. All are specified over the extended -40 $^{\circ}$ C to +125 $^{\circ}$ C temperature range.

Applications

- Imaging
- Photodiode Preamp
- DVD/CD
- Filters
- Professional Video and Cameras
- Hand Sets
- Base Stations
- A-to-D Driver





Pin Configuration

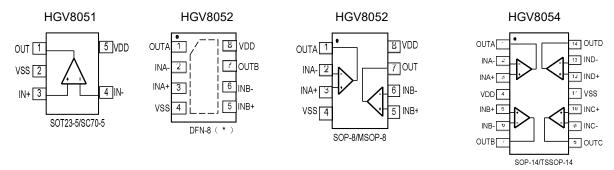


Figure 1. Pin Assignment Diagram

Absolute Maximum Ratings

Condition	Min	Max			
Power Supply Voltage (VDD to Vss)	-0.5V	+7.5V			
Analog Input Voltage (IN+ or IN-)	Vss-0.5V	VDD+0.5V			
PDB Input Voltage	Vss-0.5V	+7V			
Operating Temperature Range	-40°C	+125°C			
Junction Temperature	+16	0°C			
Storage Temperature Range	-55°C	+150°C			
Lead Temperature (soldering, 10sec)	+260°C				
Package Thermal Resistance (TA=+25℃)					
SOP-8, θJA	125°C/W				
MSOP-8, θJA	216°C/W				
SOT23-5, θJA	190°	C/W			
SC70-5, θJA	333°	C/W			
ESD Susceptibility					
НВМ	6K				
MM	400	OV			

Note:

Stress greater than those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions outside those indicated in the operational sections of this specification are not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.



Electrical Performance Characteristics

(G=+2, RF=887Ω, RG=887Ω, and RL=150Ω connected to VS/2, unless otherwise noted. Typical values are at TA=+25°C.)

				HGV	/8051/52	/54		
DADAMETED	CONDITIONS	TYP	ı	AM/NIN	OVER	TEMPER	RATURE	
PARAMETER	CONDITIONS	+25℃	+25 ℃	0℃ to70℃	-40℃to 85℃	-40℃ to125℃	UNITS	MIN/ MAX
DYNAMIC PERFORMANCE								
-3dB Small Signal Bandwidth	G = +1, Vo = 0.1V p-p, RF = 24Ω, RL = $150Ω$	180					MHz	TYP
	G = +1, Vo = 0.1V p-p, RF = 24Ω , RL = $1k\Omega$	250					MHz	TYP
	$G = +2$, $Vo = 0.1V p-p$, $RL = 50\Omega$	55					MHz	TYP
	$G = +2$, $Vo = 0.1V p-p$, $RL = 150\Omega$	93					MHz	TYP
	G = +2, Vo = 0.1V p-p, RL = $1k\Omega$	122					MHz	TYP
	$G = +2$, $Vo = 0.1V p-p$, $RL = 10k\Omega$	130					MHz	TYP
Gain-Bandwidth Product	G = +10, $RL = 150Ω$	115					MHz	TYP
	$G = +10$, $RL = 1k\Omega$	150					MHz	TYP
Bandwidth for 0.1dB Flatness	G = +2, Vo = 0.1V p-p, RL = 150 Ω , RF =887 Ω	52					MHz	TYP
Slew Rate	G = +1, 2V Output Step	77/-151					V/µs	TYP
	G = +2, 2V Output Step	88/-119					V/µs	TYP
	G = +2, 4V Output Step	93/-131					V/µs	TYP
Rise-and-Fall Time	G = +2, Vo = 0.2V _{p-p} , 10% to 90%	4.5					ns	TYP
	G = +2, Vo = 2V _{p-p} , 10% to 90%	18					ns	TYP
Settling Time to 0.1%	G = +2, 2V Output Step	50					ns	TYP
Overload Recovery Time	VIN · G = +VS	18					ns	TYP
NOISE/DISTORTION PERFORMANCE								
Input Voltage Noise	f = 1MHz	4.9					nV/ Hz	TYP
Differential Gain Error (NTSC)	$G = +2, RL = 150\Omega$	0.03					%	TYP
Differential Phase Error (NTSC)	G = +2, RL = 150Ω	0.08					degree	TYP
DC PERFORMANCE								
Input Offset Voltage (VOS)		±2	±8	±8.9	±9.5	±9.8	mV	MAX
Input Offset Voltage Drift		2					μV/°C	TYP
Input Bias Current (IB)		1					PA	TYP
Input offset Current (IOS)		2					PA	TYP
Open-Loop Gain (AOL)	V_O = 0.3V to 4.7V, R_L = 150 Ω	80	75	74	74	73	dB	MIN
	V_O = 0.2V to 4.8V, R_L = 1k Ω	104	92	91	91	80	dB	MIN
INPUT CHARACTERISTICS								
Input Common-Mode Voltage Range (VCM)	$V_{CM} = -0.1V \text{ to } +3.5V$	-0.2 to					V	TYP
Common-Mode Rejection Ratio (CMRR)		+3.8 80	66	65	65	62	dB	MIN



Electrical Performance Characteristics

(G= +2, RF=887Ω, RG=887Ω, and RL=150Ω connected to VS/2, unless otherwise noted. Typical values are at TA =+25°C.)

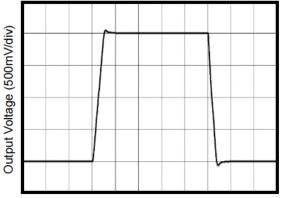
				HGV80	51/52/54	1		
PARAMETER	CONDITIONS	TYP	MIN/MAX OVER TEMPERATU					
PARAIVIETER	CONDITIONS	+25℃	+25℃	0℃ to70℃	-40℃to 85℃	-40℃ to125℃	UNITS	MIN/ MAX
OUTPUT CHARACTERISTICS								
Output Voltage Swing from Rail	R _L = 150Ω	0.12					V	TYP
	$R_L = 1k\Omega$	0.03					V	TYP
Output Current		80	60				mA	MIN
Closed-Loop Output Impedance	f<100kHz	0.08					Ω	TYP
POWER-DOWN DISABLE								
(HGV8051/2 only)								
Turn-On Time		236					ns	TYP
Turn-Off Time		52					ns	TYP
DISABLE Voltage-Off			0.8				V	MAX
DISABLE Voltage-On			2				V	MIN
POWER SUPPLY								
Operating Voltage Range			2.5	2.7	2.7	2.7	V	MIN
			5.5	5.5	5.5	5.5	V	MAX
Quiescent Current (per amplifier)		2.8	3.65				mA	MAX
Supply Current when Disabled per		50	70	85	100	137	μA	MAX
amplifier(HGV8051/2 only)								
Power Supply Rejection Ratio (PSRR)	Δ VS = +2.7V to +5.5V, VCM = (-VS) +0.5	80	67	67	65	62	dB	MIN



Typical Performance characteristics

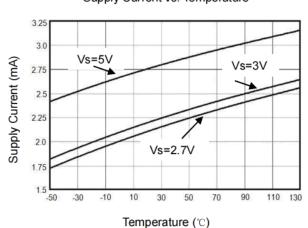
 $(Vs=+5V,G=+2,\,RF=887\Omega,RG=887\Omega,and\,\,RL=150\Omega connected\,\,to\,\,Vs/2,\,Typical\,\,values\,\,are\,\,at\,\,TA=+25^{\circ}C.)$



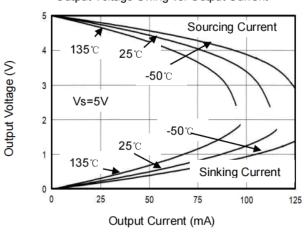


Time (50ns/div)

Supply Current vs. Temperature



Output Voltage Swing vs. Output Current

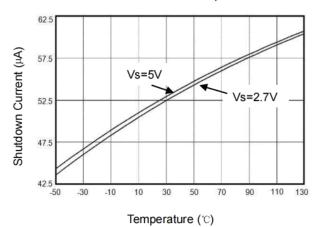


Non-Inverting Small-Signal Step Response

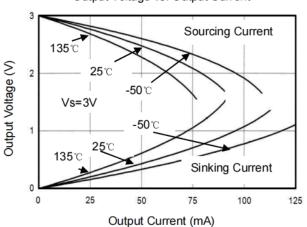


Time (50ns/div)

Sutdown Current vs. Temperature



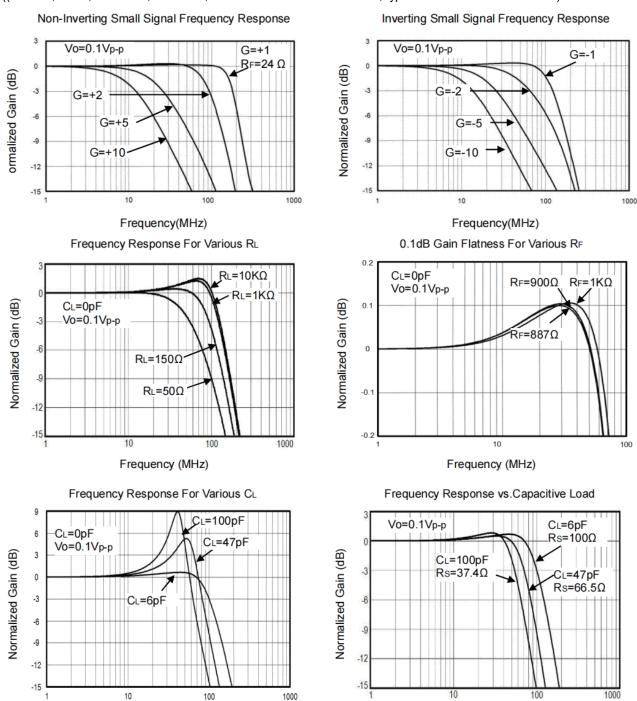
Output Voltage vs. Output Current





Typical Performance characteristics

((Vs=+5V,G= +2, RF=887 Ω ,RG=887 Ω ,and RL=150 Ω connected to Vs/2,Typical values are at TA =+25°C.)



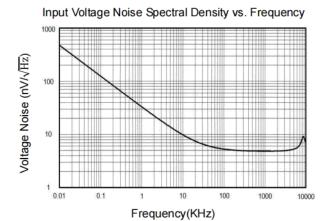
Frequency (MHz)

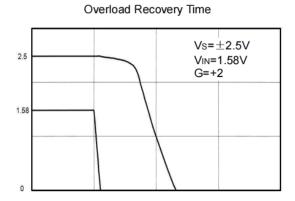
Frequency (MHz)



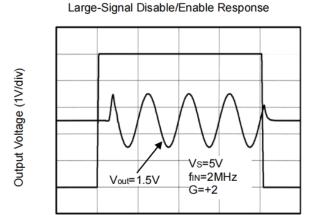
Typical Performance characteristics

 $(Vs=+5V,G=+2,RF=887\Omega,RG=887\Omega,andRL=150\Omega)$ connected to Vs/2, Typical values are at TA=+25°C.)

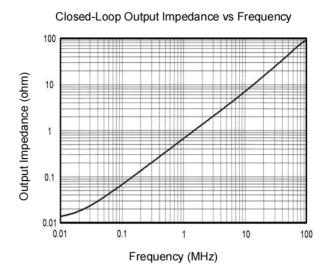




Time(25ns/div)



Time (500n/div)





Application Note

Driving Capacitive Loads

HGV805X series op amps are unity-gain stable and suitable for a wide range of general-purpose applications. The small footprints of the HGV805X series packages save space on printed circuit boards and enable the design of smaller electronic products.

Power Supply Bypassing and Board Layout

HGV805X series operates from a single 2.5V to 5.5V supply or dual ± 1.25 V to ± 2.75 V supplies. For best performance, a 0.1 μ F ceramic capacitor should be placed close to the VDD pin in single supply operation. For dual supply operation, both VDD and VSS supplies should be bypassed to ground with separate 0.1 μ F ceramic capacitors.

Low Supply Current

The low supply current (typical 2.8mA per channel) of HGV805X series will help to maximize battery life. They are ideal for battery powered systems.

Operating Voltage

HGV805X series operate under wide input supply voltage (2.5V to 5.5V). In addition, all temperature specifications apply from

-40°C to +125°C. Most behavior remains unchanged throughout the full operating voltage range. These guarantees ensure operation throughout the single Li-Ion battery lifetime.

Rail-to-Rail Output

Rail-to-Rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating in low supply voltages. The output voltage of HGV805X series can typically swing to less than 8mV from supply rail in light resistive loads ($>1k\Omega$), and 30mV of supply rail in moderate resistive loads (150Ω).

Capacitive Load Tolerance

The HGV805X family is optimized for bandwidth and speed, not for driving capacitive loads. Output capacitance will create a pole in the amplifier's feedback path, leading to excessive peaking and potential oscillation. If dealing with load capacitance is a requirement of the application, the two strategies to consider are (1) using a small resistor in series with the amplifier's output and the load capacitance and (2) reducing the bandwidth of the amplifier's feedback loop by increasing the overall noise gain. Figure 2. shows a unity gain follower using the series resistor strategy. The resistor isolates the output from the capacitance and, more importantly, creates a zero in the feedback path that compensates for the pole created by the output capacitance.

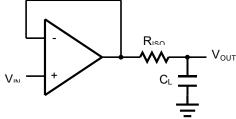


Figure 2. Indirectly Driving a Capacitive Load Using Isolation Resistor



The bigger the RISO resistor value, the more stable VOUT will be. However, if there is a resistive load RL in parallel with the capacitive load, a voltage divider (proportional to RISO/RL) is formed, this will result in a gain error.

The circuit in Figure 3 is an improvement to the one in Figure 2. RF provides the DC accuracy by feed-forward the VIN to RL. CF and RISO serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving the phase margin in the overall feedback loop. Capacitive drive can be increased by increasing the value of CF. This in turn will slow down the pulse response.

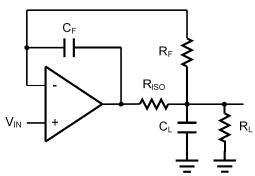


Figure 3. Indirectly Driving a Capacitive Load with DC Accuracy

Typical Application Circuits

Differential amplifier

The differential amplifier allows the subtraction of two input voltages or cancellation of a signal common the two inputs. It is useful as a computational amplifier in making a differential to single-end conversion or in rejecting a common mode signal. Figure 4. shown the differential amplifier using HGV805X.

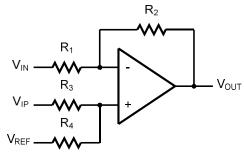


Figure 4. Differential Amplifier

$$V_{\text{OUT}} = \left(\frac{R_1 + R_2}{R_2 + R_4}\right) \frac{R_4}{R_1} V_{\text{IN}} - \frac{R_2}{R_1} V_{\text{IP}} + \left(\frac{R_1 + R_2}{R_2 + R_4}\right) \frac{R_2}{R_1} V_{\text{REF}}$$

If the resistor ratios are equal (i.e. $R_1 = R_3$ and $R_2 = R_4$), then

$$V_{\text{OUT}} = \frac{R_2}{R_1} (V_{\text{IP}} - V_{\text{IN}}) + V_{\text{REF}}$$



Low Pass Active Filter

The low pass active filter is shown in Figure 5. The DC gain is defined by -R2/R1. The filter has a -20dB/decade roll-off after its corner frequency $fC=1/(2\pi R3C1)$.

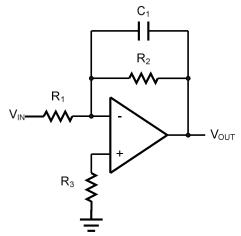


Figure 5. Low Pass Active Filter

Driving Video

The HGV805X can be used in video applications like in Figure 6.

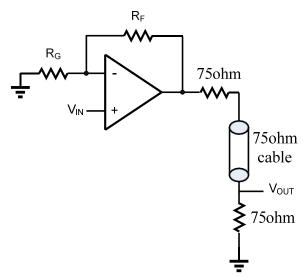
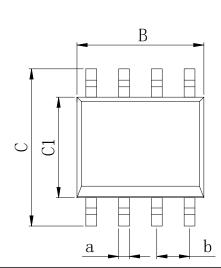
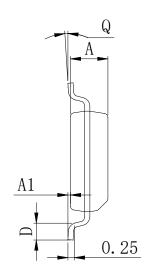


Figure 6. Typical video driving



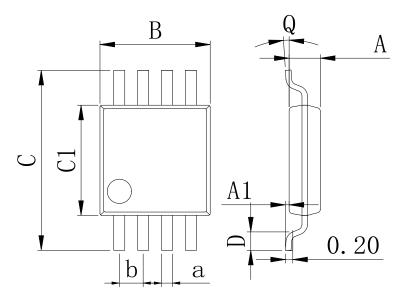
SOP8





Dimensions In Mill	Dimensions In Millimeters(SOP8)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b			
Min:	1.35	0.05	4.90	5.80	3.80	0.40	0°	0.35	1.27 BSC			
Max:	1.55	0.20	5.10	6.20	4.00	0.80	8°	0.45	1.27 BSC			

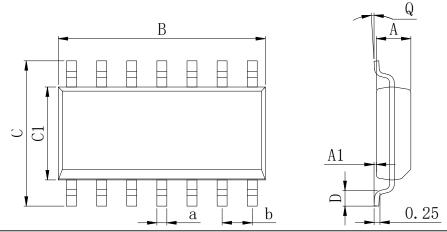
MSOP8



Dimensions In Millimeters(MSOP8)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b		
Min:	0.80	0.05	2.90	4.75	2.90	0.35	0°	0.25	0.65 BSC		
Max:	0.90	0.20	3.10	5.05	3.10	0.75	8°	0.35	0.00 650		

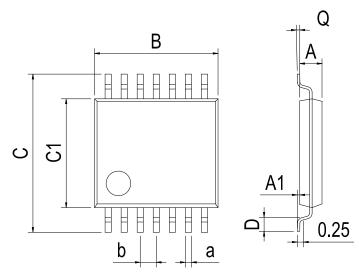


SOP14



Dimensions In Millimeters(SOP14)											
Symbol:	Α	A1	В	С	C1	D	Q	а	b		
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	1.27 BSC		
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 650		

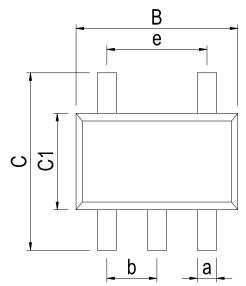
TSSOP14

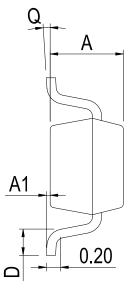


Dimensions In Millimeters(TSSOP14)											
Symbol:	А	A1	В	С	C1	D	Q	а	b		
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65 BSC		
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.00 650		



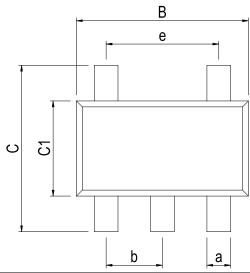
SOT23-5

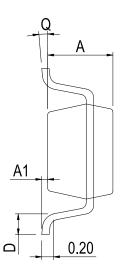




Dimensions In Millimeters(SOT23-5)												
Symbol:	Α	A1	В	С	C1	D	Q	а	b	е		
Min:	1.05	0.00	2.82	2.65	1.50	0.30	0°	0.30	0.05 BSC	1 00 BSC		
Max:	1.15	0.15	3.02	2.95	1.70	0.60	8°	0.40	0.95 BSC	1.90 BSC		

SC70-5

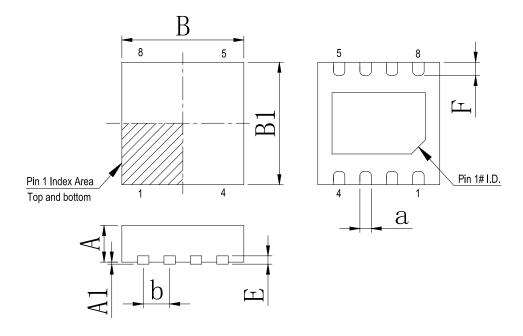




Dimensions I	Dimensions In Millimeters(SC70-5)												
Symbol:	Α	A1	В	С	C1	D	Q	а	b	е			
Min:	0.90	0.00	2.00	2.15	1.15	0.26	0°	0.30	0.65 BSC	1.30 BSC			
Max:	1.00	0.15	2.20	2.45	1.35	0.46	8°	0.40	0.00 000	1.30 030			



DFN-8 4*4



Dimensions In Millimeters(DFN-8L 4*4)											
Symbol:	А	A1	В	D	Е	F	а	а			
Min:	3.9	3.9	0.80	0.0	0.23	0.30	0.20	0.80TYP			
Max:	4.1	4.1	1.0	0.05	0.30	0.50	0.34	0.0011P			

HGV8051/8052/8054

IMPORTANT STATEMENT:

Huaguan Semiconductor reserves the right to change its products and services without notice. Before ordering, the customer shall obtain the latest relevant information and verify whether the information is up to date and complete. Huaguan Semiconductor does not assume any responsibility or obligation for the altered documents.

Customers are responsible for complying with safety standards and taking safety measures when using Huaguan Semiconductor products for system design and machine manufacturing. You will bear all the following responsibilities: select the appropriate Huaguan Semiconductor products for your application; Design, validate and test your application; Ensure that your application meets the appropriate standards and any other safety, security or other requirements. To avoid the occurrence of potential risks that may lead to personal injury or property loss.

Huaguan Semiconductor products have not been approved for applications in life support, military, aerospace and other fields, and Huaguan Semiconductor will not bear the consequences caused by the application of products in these fields.

The technical and reliability data (including data sheets), design resources (including reference designs), application or other design suggestions, network tools, safety information and other resources provided for the performance of semiconductor products produced by Huaguan Semiconductor are not guaranteed to be free from defects and no warranty, express or implied, is made. The use of testing and other quality control technologies is limited to the quality assurance scope of Huaguan Semiconductor. Not all parameters of each device need to be tested.

The documentation of Huaguan Semiconductor authorizes you to use these resources only for developing the application of the product described in this document. You have no right to use any other Huaguan Semiconductor intellectual property rights or any third party intellectual property rights. It is strictly forbidden to make other copies or displays of these resources. You should fully compensate Huaguan Semiconductor and its agents for any claims, damages, costs, losses and debts caused by the use of these resources. Huaguan Semiconductor accepts no liability for any loss or damage caused by infringement.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Operational Amplifiers - Op Amps category:

Click to view products by HGSEMI manufacturer:

Other Similar products are found below:

SC2902DTBR2G LM358SNG 430227FB UPC451G2-A UPC824G2-A LT1678IS8 042225DB 058184EB UPC822G2-A UPC258G2-A NCS5651MNTXG NCV33202DMR2G NJM324E NTE925 5962-9080901MCA* AZV358MTR-G1 AP4310AUMTR-AG1

HA1630D02MMEL-E HA1630S01LPEL-E AZV358MMTR-G1 SCY33178DR2G NJU77806F3-TE1 NCV5652MUTWG NCV20034DR2G

NTE778S NTE871 NTE924 NTE937 MCP6V16UT-E/OT MCP6V17T-E/MS MCP6V19T-E/ST SCY6358ADR2G NCS20282FCTTAG

LM4565FVT-GE2 EL5420CRZ-T7A TSV772IQ2T TSV792IYST NJM2100M-TE1 COS2262MR COS2252MR COS5532SRB

COS2272MR LMV358MR COS6002MR LMV358SR LM358SR RC4580MM/TR HGV8544M/TR HGV8541M/TR HGV8634M/TR